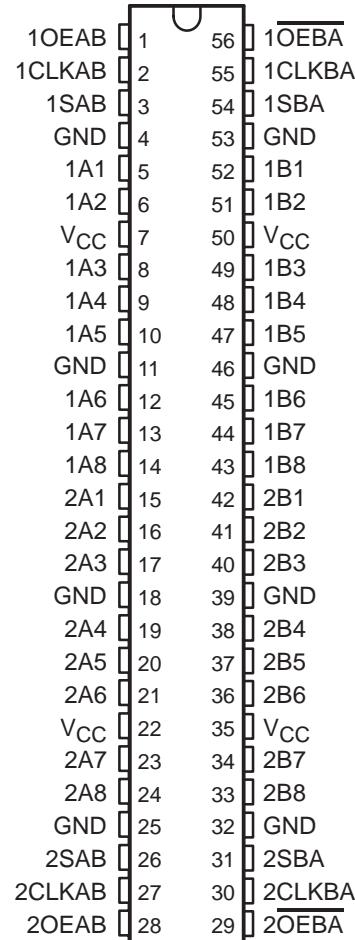


- **Members of the Texas Instruments *Widebus*™ Family**
- **State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation**
- **Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})**
- **Support Unregulated Battery Operation Down to 2.7 V**
- **Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$**
- **I_{off} and Power-Up 3-State Support Hot Insertion**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Latch-Up Performance Exceeds 500 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)**
- **Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54LVTH16652 . . . WD PACKAGE
SN74LVTH16652 . . . DGG OR DL PACKAGE
(TOP VIEW)



description

The 'LVTH16652 devices are 16-bit bus transceivers designed for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices can be used as two 8-bit transceivers or one 16-bit transceiver.

Output-enable (OEAB and $\overline{\text{OEBA}}$) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select whether real-time or stored data is transferred. A low input level selects real-time data, and a high input level selects stored data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'LVTH16652 devices.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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**SN54LVTH16652, SN74LVTH16652
3.3-V ABT 16-BIT BUS TRANSCEIVERS AND REGISTERS
WITH 3-STATE OUTPUTS**

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description (continued)

Data on the A or B bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) inputs, regardless of the levels on the select-control or output-enable inputs. When SAB and SBA are in the real-time transfer mode, it also is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and \overline{OEBA} . In this configuration, each output reinforces its input. When all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last level configuration.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor and OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH16652 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LVTH16652 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE

INPUTS						DATA I/O [†]		OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	↑	↑	X	X	Input	Input	Store A and B data
X	H	↑	H or L	X	X	Input	Unspecified [‡]	Store A, hold B
H	H	↑	↑	X [‡]	X	Input	Output	Store A in both registers
L	X	H or L	↑	X	X	Unspecified [‡]	Input	Hold A, store B
L	L	↑	↑	X	X [‡]	Output	Input	Store B in both registers
L	L	X	X	X	L	Output	Input	Real-time B data to A bus
L	L	X	H or L	X	H	Output	Input	Stored B data to A bus
H	H	X	X	L	X	Input	Output	Real-time A data to B bus
H	H	H or L	X	H	X	Input	Output	Stored A data to B bus
H	L	H or L	H or L	H	H	Output	Output	Stored A data to B bus and stored B data to A bus

[†] The data-output functions may be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data-input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

[‡] Select control = L; clocks can occur simultaneously.

Select control = H; clocks must be staggered to load both registers.



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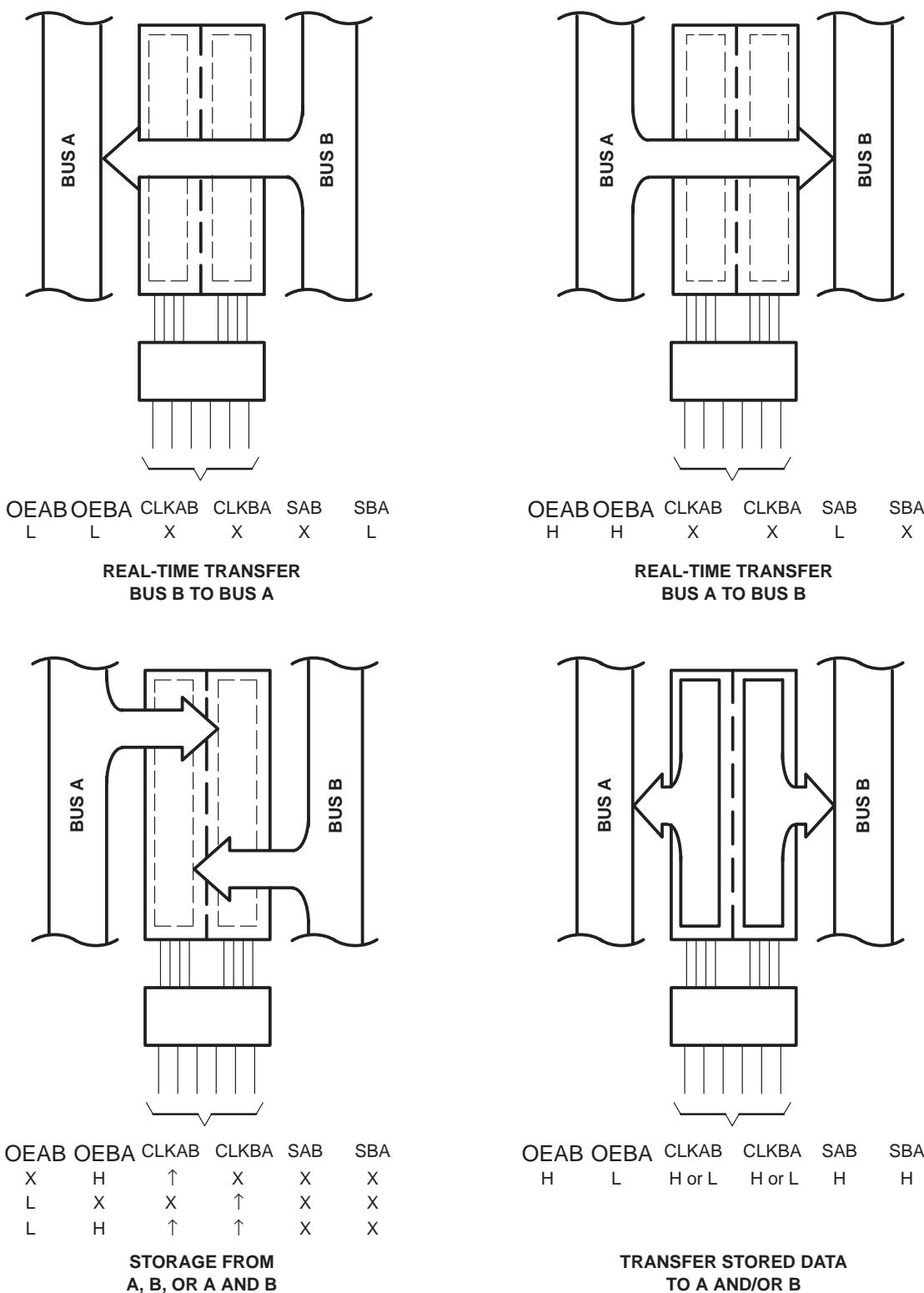
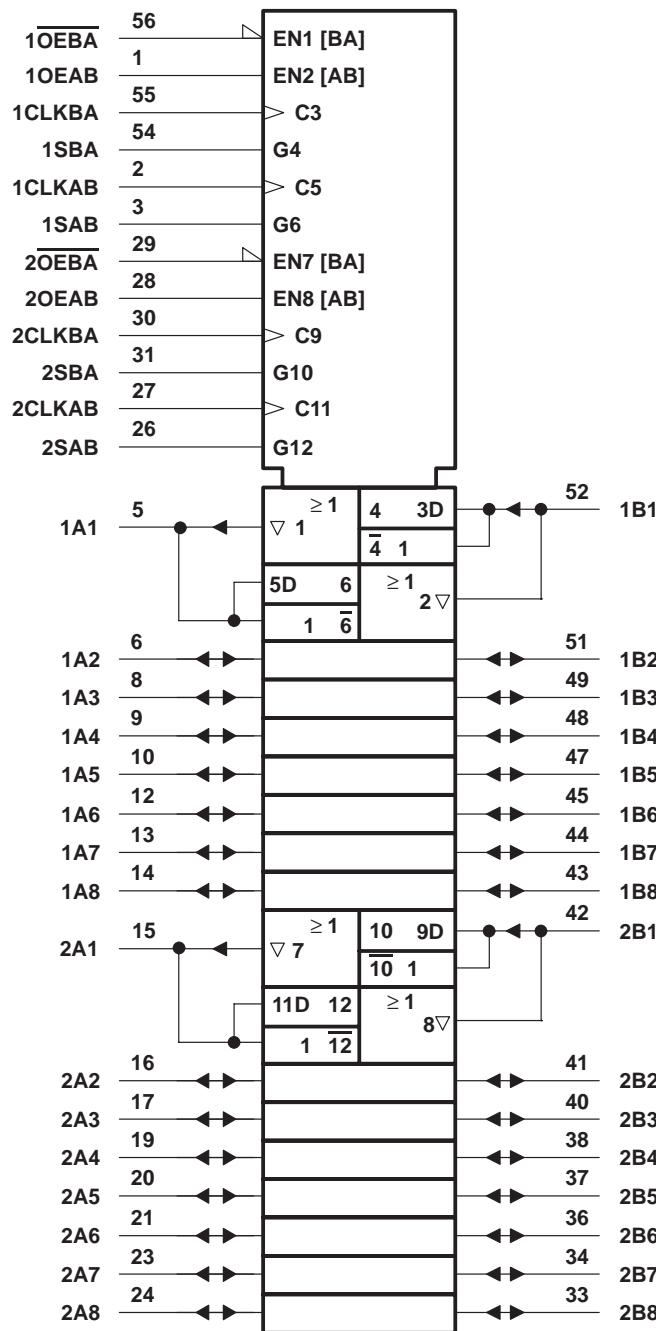


Figure 1. Bus-Management Functions

**SN54LVTH16652, SN74LVTH16652
3.3-V ABT 16-BIT BUS TRANSCEIVERS AND REGISTERS
WITH 3-STATE OUTPUTS**

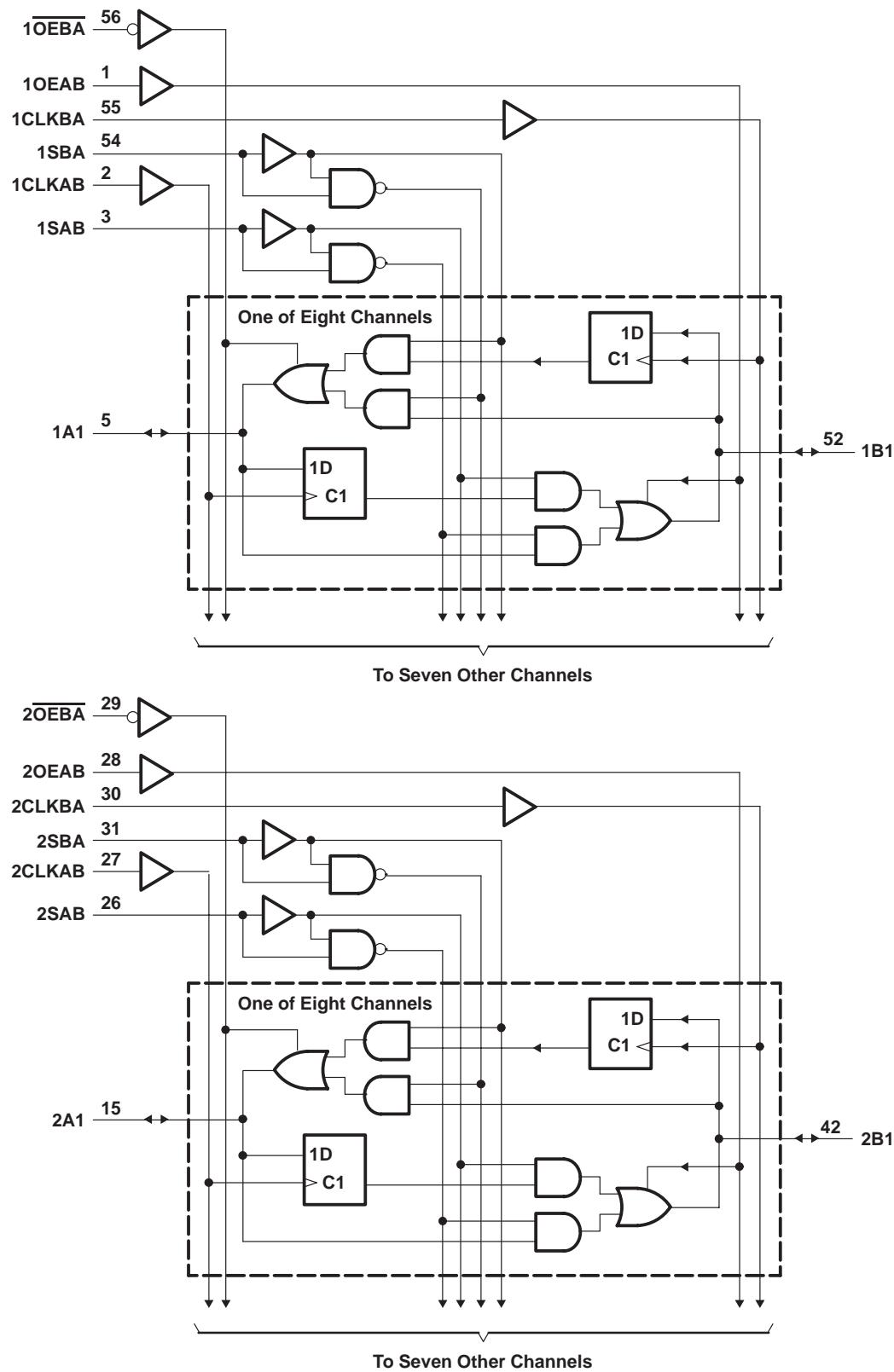
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



SN54LVTH16652, SN74LVTH16652 3.3-V ABT 16-BIT BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		SN54LVTH16652		SN74LVTH16652		UNIT	
		MIN	MAX	MIN	MAX		
V _{CC}	Supply voltage	2.7	3.6	2.7	3.6	V	
V _{IH}	High-level input voltage	2		2		V	
V _{IL}	Low-level input voltage		0.8		0.8	V	
V _I	Input voltage		5.5		5.5	V	
I _{OH}	High-level output current		-24		-32	mA	
I _{OL}	Low-level output current		48		64	mA	
Δt/Δv	Input transition rise or fall rate	Outputs enabled		10	10	ns/V	
Δt/ΔV _{CC}	Power-up ramp rate		200	200		μs/V	
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SN54LVTH16652, SN74LVTH16652
3.3-V ABT 16-BIT BUS TRANSCEIVERS AND REGISTERS
WITH 3-STATE OUTPUTS
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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	SN54LVTH16652			SN74LVTH16652			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}	$V_{CC} = 2.7 \text{ V}$, $I_I = -18 \text{ mA}$			-1.2			-1.2	V
V_{OH}	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$, $I_{OH} = -100 \mu\text{A}$	$V_{CC} - 0.2$			$V_{CC} - 0.2$			V
	$V_{CC} = 2.7 \text{ V}$, $I_{OH} = -8 \text{ mA}$	2.4			2.4			
	$V_{CC} = 3 \text{ V}$	$I_{OH} = -24 \text{ mA}$	2				2	
		$I_{OH} = -32 \text{ mA}$						
V_{OL}	$V_{CC} = 2.7 \text{ V}$	$I_{OL} = 100 \mu\text{A}$		0.2		0.2		V
		$I_{OL} = 24 \text{ mA}$		0.5		0.5		
	$V_{CC} = 3 \text{ V}$	$I_{OL} = 16 \text{ mA}$		0.4		0.4		
		$I_{OL} = 32 \text{ mA}$		0.5		0.5		
		$I_{OL} = 48 \text{ mA}$		0.55				
		$I_{OL} = 64 \text{ mA}$				0.55		
	I_I	$V_{CC} = 0 \text{ or } 3.6 \text{ V}$, $V_I = 5.5 \text{ V}$		10		10		μA
		$V_{CC} = 3.6 \text{ V}$, $V_I = V_{CC} \text{ or GND}$		± 1		± 1		
		$V_{CC} = 3.6 \text{ V}$	$V_I = 5.5 \text{ V}$	20		20		
			$V_I = V_{CC}$	1		1		
			$V_I = 0$	-5		-5		
I_{off}	$V_{CC} = 0$, $V_I \text{ or } V_O = 0 \text{ to } 4.5 \text{ V}$				± 100		μA	
$I_I(\text{hold})$	$A \text{ or } B \text{ ports}$	$V_{CC} = 3 \text{ V}$	$V_I = 0.8 \text{ V}$	75		75		μA
			$V_I = 2 \text{ V}$	-75		-75		
		$V_{CC} = 3.6 \text{ V}^\$$	$V_I = 0 \text{ to } 3.6 \text{ V}$			± 500		
I_{OZPU}	$V_{CC} = 0 \text{ to } 1.5 \text{ V}$, $V_O = 0.5 \text{ V to } 3 \text{ V}$, $\text{OE/OE} = \text{don't care}$			$\pm 100^*$		± 100	μA	
I_{OZPD}	$V_{CC} = 1.5 \text{ V to } 0$, $V_O = 0.5 \text{ V to } 3 \text{ V}$, $\text{OE/OE} = \text{don't care}$			$\pm 100^*$		± 100	μA	
I_{CC}	$V_{CC} = 3.6 \text{ V}$, $I_O = 0$, $V_I = V_{CC} \text{ or GND}$	Outputs high		0.19		0.19		mA
		Outputs low		5		5		
		Outputs disabled		0.19		0.19		
$\Delta I_{CC}^\#$	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$, One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND			0.2		0.2	mA	
C_I	$V_I = 3 \text{ V or } 0$		4		4		pF	
C_{IO}	$V_O = 3 \text{ V or } 0$		10		10		pF	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^\circ\text{C}$.

‡ Unused pins at V_{CC} or GND

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



SN54LVTH16652, SN74LVTH16652**3.3-V ABT 16-BIT BUS TRANSCEIVERS AND REGISTERS****WITH 3-STATE OUTPUTS**

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

			SN54LVTH16652				SN74LVTH16652				UNIT	
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 ± 0.3 V		V _{CC} = 2.7 V			
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
f _{clock}	Clock frequency			150	150	150	150	150	150	150	MHz	
t _W	Pulse duration, CLK high or low			3.3	3.3	3.3	3.3	3.3	3.3	3.3	ns	
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	Data high	1.2		1.5		1.2		1.5		ns	
		Data low	2		2.8		2		2.8			
t _h	Hold time, A or B after CLKAB↑ or CLKBA↑	Data high	0.5		0		0.5		0		ns	
		Data low	0.5		0.5		0.5		0.5			

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH16652				SN74LVTH16652				UNIT	
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V			
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN		
f _{max}			150		150		150		150	150	MHz	
t _{PLH}	CLK	B or A	1.3	4.5		5	1.3	2.7	4.2		ns	
			1.3	4.5		5	1.3	2.8	4.2			
t _{PHL}	A or B	B or A	1	3.6		4.1	1	2.4	3.4		ns	
			1	3.6		4.1	1	2.1	3.4			
t _{PLH}	SAB or SBA	B or A	1	4.7		5.6	1	2.7	4.5		ns	
			1	4.7		5.6	1	3	4.5			
t _{PZH}	OEBA	A	1	4.5		5.4	1	2.4	4.3		ns	
			1	4.5		5.4	1	2.3	4.3			
t _{PZL}	OEBA	A	2	5.8		6.3	2	3.9	5.6		ns	
			2	5.6		6.3	2	3.4	5.4			
t _{PHZ}	OEAB	B	1.3	4.4		5.1	1.3	2.7	4.2		ns	
			1.3	4.4		5.1	1.3	2.6	4.2			
t _{PZL}	OEAB	B	1.6	5.8		6.5	1.3	3.5	5.5		ns	
			1.6	5.8		6.5	1.3	3.2	5.5			

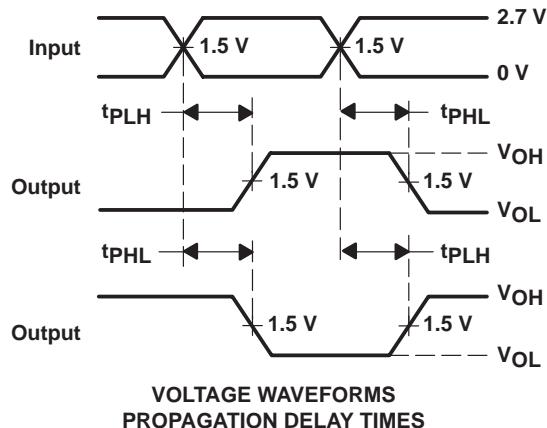
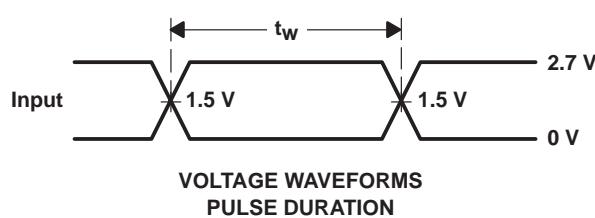
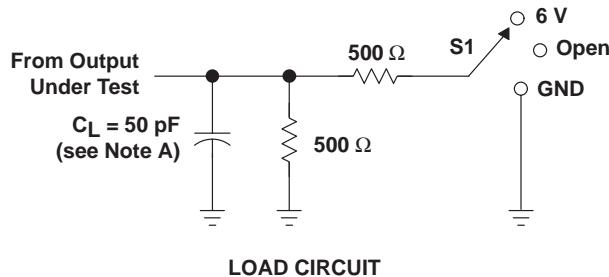
† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

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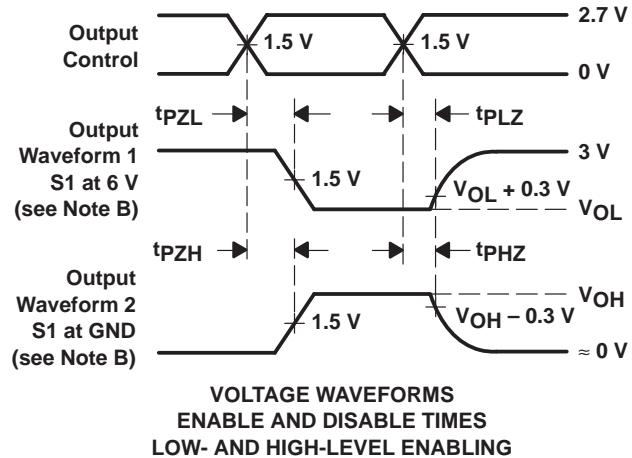
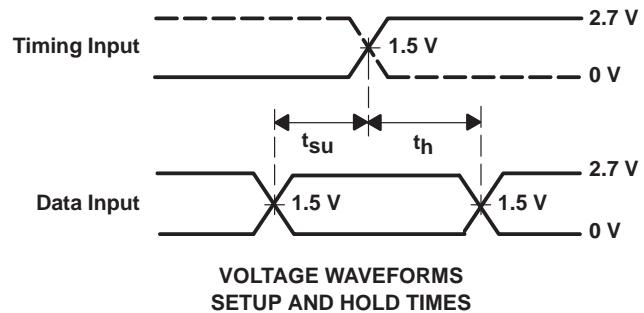


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PARAMETER MEASUREMENT INFORMATION



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



NOTES:

- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
- The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVTH16652DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16652	Samples
SN74LVTH16652DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16652	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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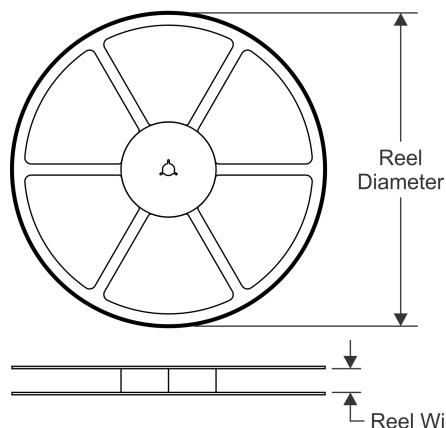
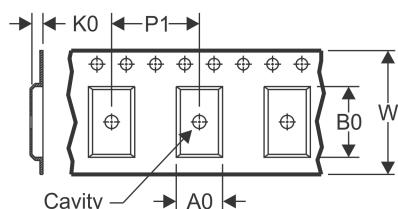
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVTH16652 :

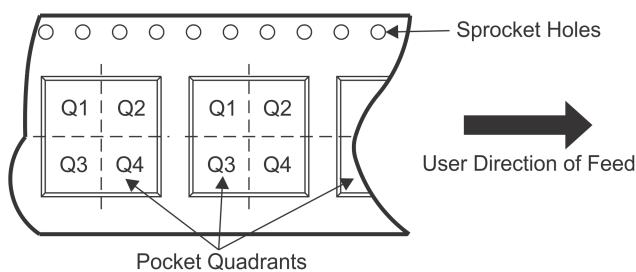
- Enhanced Product: [SN74LVTH16652-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

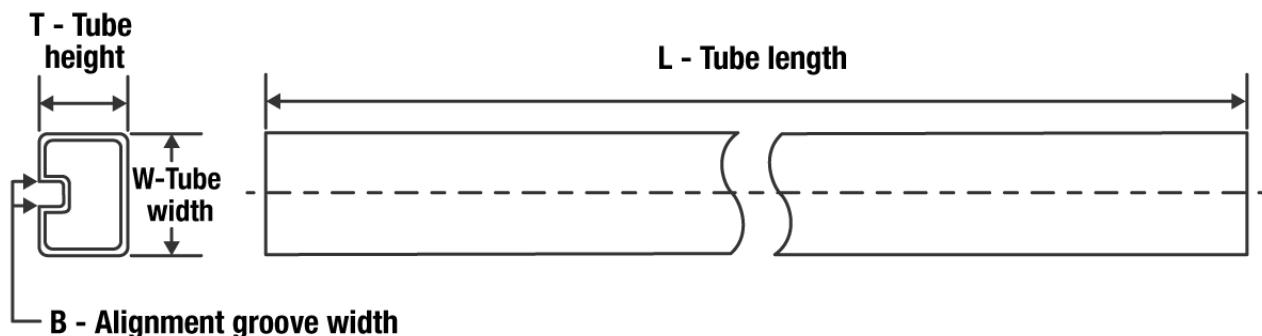
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH16652DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH16652DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0

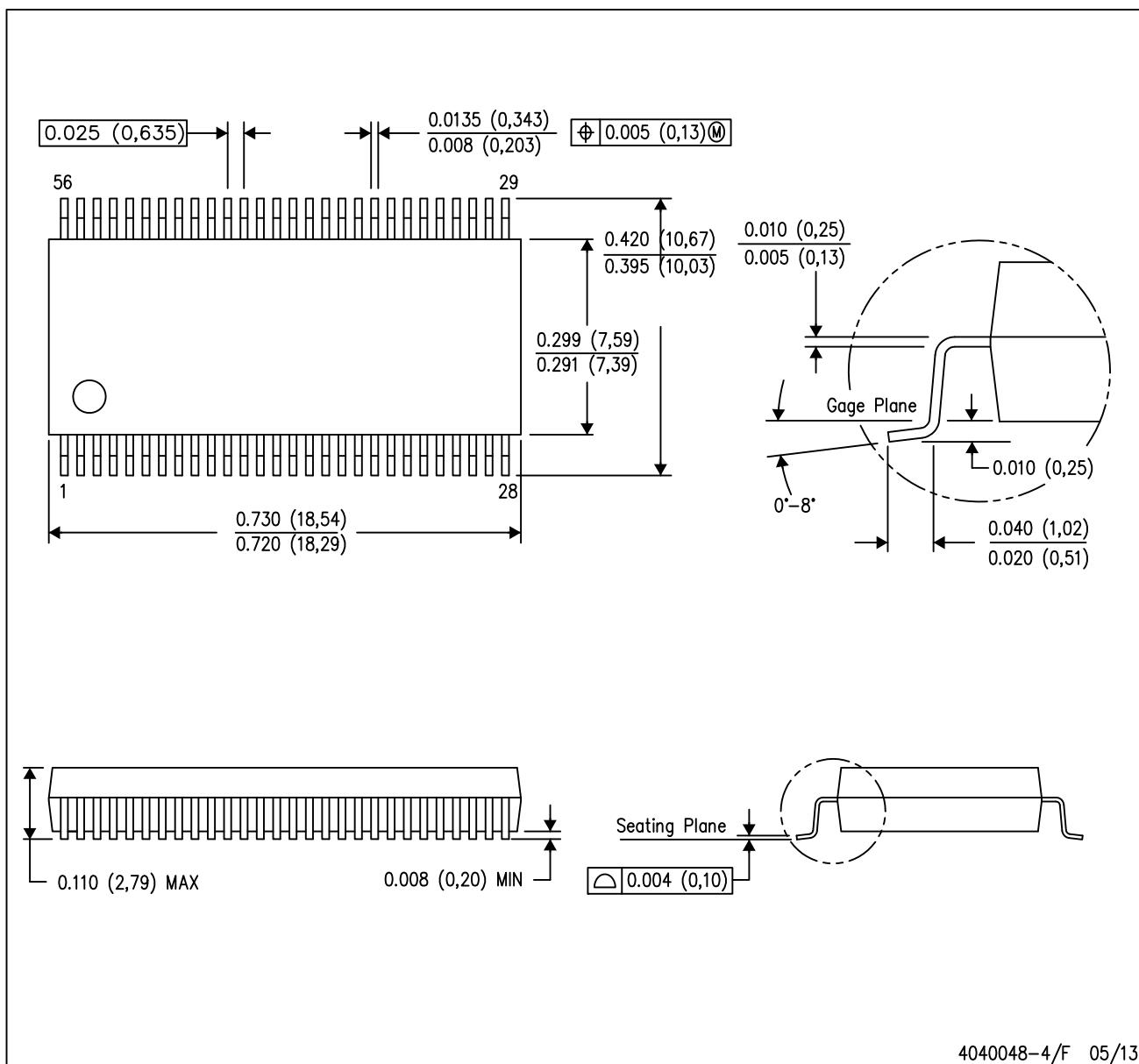
TUBE

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74LVTH16652DL	DL	SSOP	56	20	473.7	14.24	5110	7.87

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0.15).
- Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.

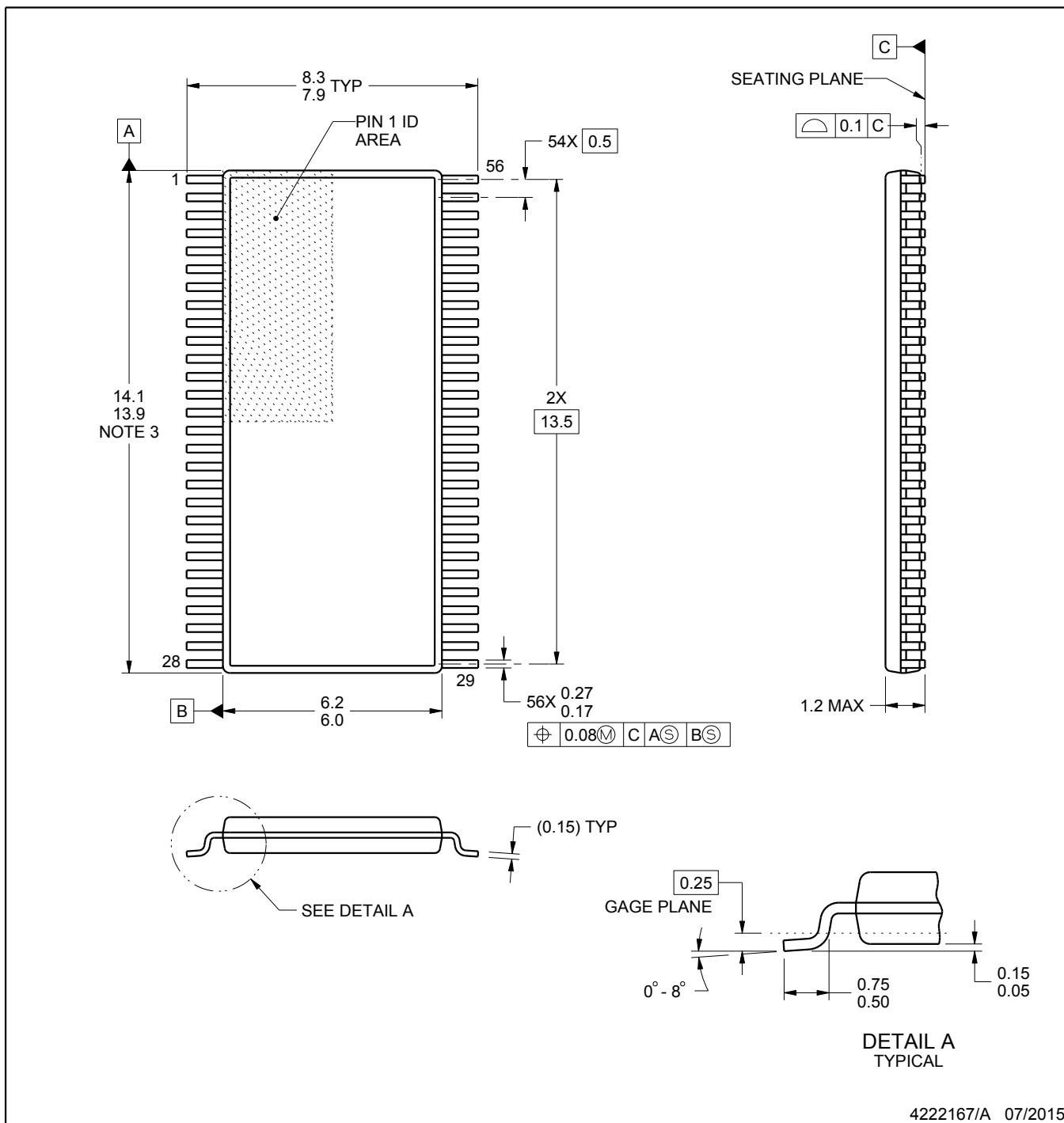
PACKAGE OUTLINE

DGG0056A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

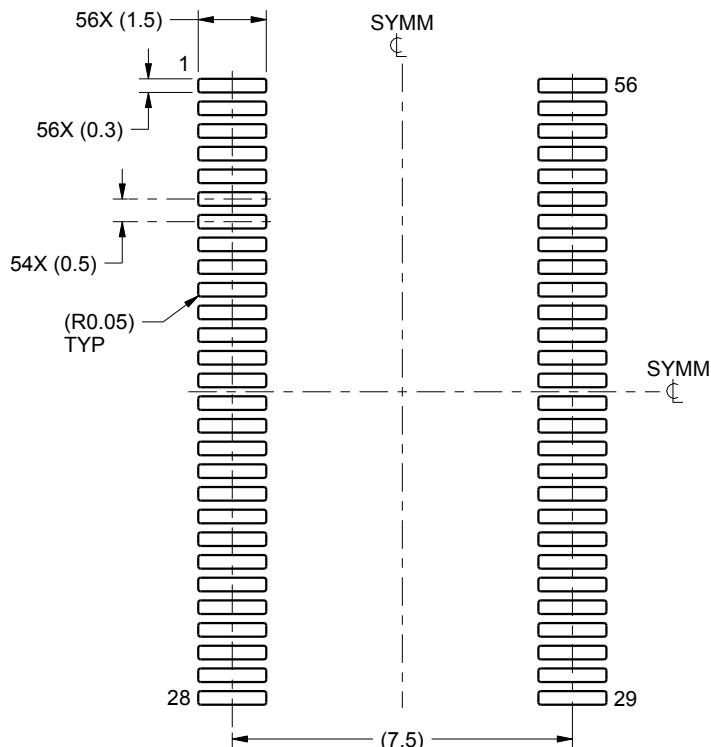
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

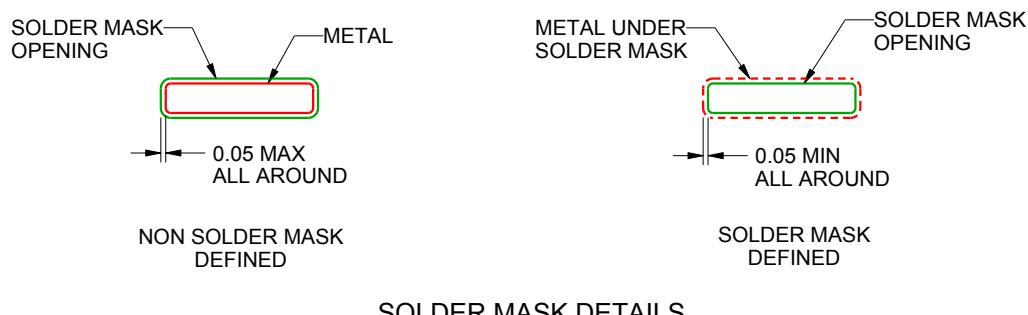
DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4222167/A 07/2015

NOTES: (continued)

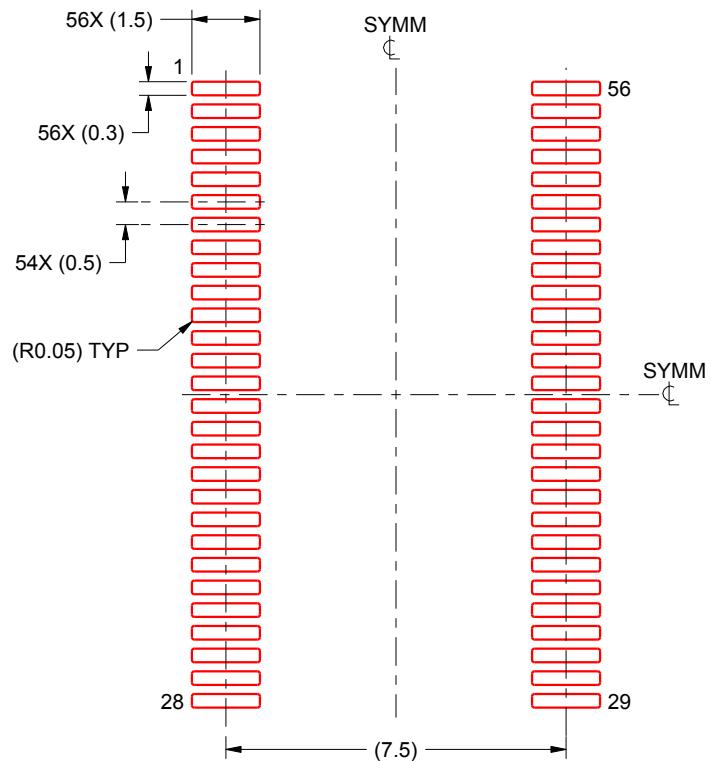
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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